



ChargePump™ High Current Charge Pump with Dual LDO for Backlight Applications

General Description

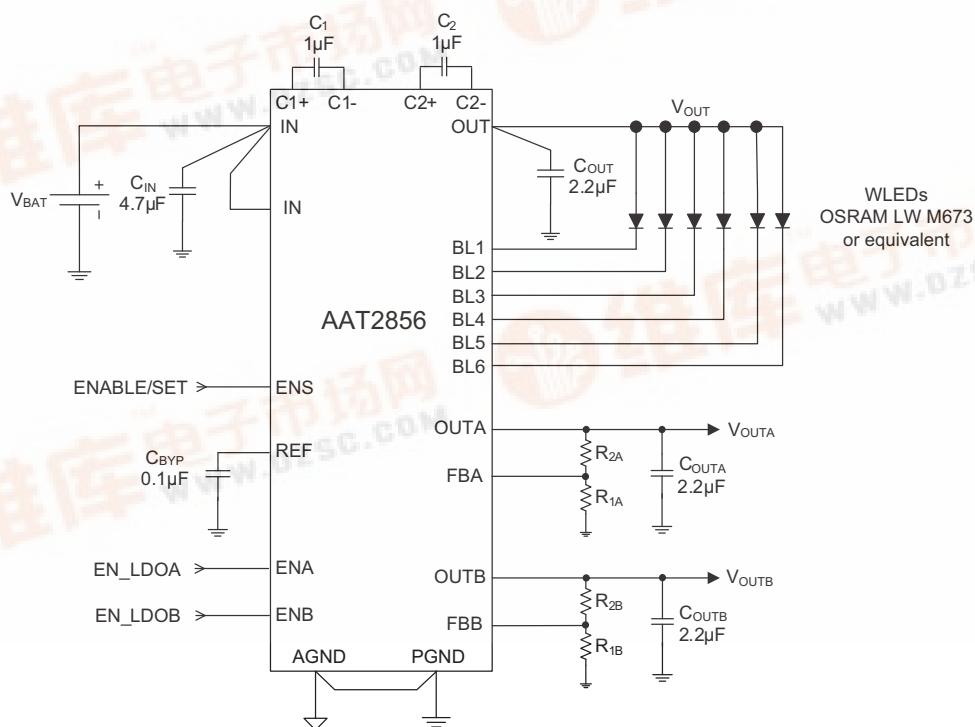
The AAT2856 is a highly integrated charge pump with dual linear regulators optimized for systems powered from lithium-ion/polymer batteries. The charge pump provides power for white LED backlight. Six backlight LEDs can be driven at up to 30mA. AnalogicTech's AS²Cwire™ (Advanced Simple Serial Control™) single-wire interface is used to enable, disable, and set the current to one of 32 levels for the backlight. Backlight current matching is 1% for uniform display brightness.

The AAT2856 offers two high-performance low-noise MicroPower™ low dropout (LDO) linear regulators. Both regulators use individual enable inputs and each will supply up to 200mA load current. LDO ground pin current is only 80 μ A, making the AAT2856 ideal for battery-operated applications.

The AAT2856 is equipped with built-in short-circuit and over-temperature protection. The soft start circuitry prevents excessive inrush current at start-up and mode transitions.

The AAT2856 is available in a Pb-free TQFN44-28 package and operates over the -40°C to +85°C ambient temperature range.

Typical Application



Features

- Input Voltage Range: 2.7V to 5.5V
- Tri-Mode Charge Pump:
 - Drives up to Six Backlight LEDs
 - 32 Programmable Backlight Current Settings Ranging from 115 μ A to 30mA
 - 2MHz Switching Frequency
- Two Linear Regulators:
 - 200mA Output Current
 - 200mV Dropout Voltage
 - Output Voltage Adjustable from 1.2V to V_{BATTERY}
 - Output Auto-Discharge for Fast Shutdown
 - Individual LDO Enable Inputs
- Built-In Thermal Protection
- Automatic Soft Start
- -40°C to +85°C Temperature Range
- TQFN44-28 Package

Applications

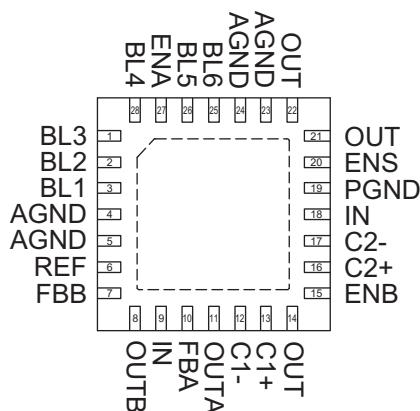
- Camera-Enabled Mobile Devices
- Digital Still Cameras
- Multimedia Mobile Phones

ChargePump™ High Current Charge Pump with Dual LDO for Backlight Applications
Pin Descriptions

| Pin # | Symbol | Description |
|--------------|--------|---|
| 1 | BL3 | Backlight LED 3 current sink. BL3 controls the current through backlight LED 3. Connect the cathode of backlight LED 3 to BL3. If not used, connect BL3 to OUT. |
| 2 | BL2 | Backlight LED 2 current sink. BL2 controls the current through backlight LED 2. Connect the cathode of backlight LED 2 to BL2. If not used, connect BL2 to OUT. |
| 3 | BL1 | Backlight LED 1 current sink. BL1 controls the current through backlight LED 1. Connect the cathode of backlight LED 1 to BL1. If not used, connect BL1 to OUT. |
| 4, 5, 23, 24 | AGND | Analog ground. Connect AGND to PGND at a single point as close to the AAT2856 as possible. |
| 6 | REF | Reference output. Bypass REF to AGND with a 0.1µF or larger ceramic capacitor. |
| 7 | FBB | Feedback input for LDO B. FBB measures the output voltage of LDO B. Connect a resistive voltage divider from the output of LDO B to FBB. FBB feedback regulation voltage is 1.2V. |
| 8 | OUTB | LDO B regulated voltage output. OUTB is the voltage output of LDO B. Bypass OUTB to AGND with a 2.2µF or larger ceramic capacitor as close to the AAT2856 as possible. |
| 9, 18 | IN | Power input. Connect IN to the input source voltage. Bypass IN to PGND with a 4.7µF or larger ceramic capacitor as close to the AAT2856 as possible. |
| 10 | FBA | Feedback input for LDO A. FBA measures the output voltage of LDO A. Connect a resistive voltage divider from the output of LDO A to FBA. FBA feedback regulation voltage is 1.2V. |
| 11 | OUTA | LDO A regulated voltage output. OUTA is the voltage output of LDO A. Bypass OUTA to AGND with a 2.2µF or larger ceramic capacitor as close to the AAT2856 as possible. |
| 12 | C1- | Negative node of charge pump capacitor 1. Connect the 1µF charge pump capacitor 1 from C1+ to C1-. |
| 13 | C1+ | Positive node of charge pump capacitor 1. Connect the 1µF charge pump capacitor 1 from C1+ to C1-. |
| 14, 21, 22 | OUT | Charge pump output; supplies current to the backlight LEDs. Connect the backlight LED anodes to OUT. Bypass OUT to PGND with a 2.2µF or larger ceramic capacitor as close to the AAT2856 as possible. |
| 15 | ENB | LDO B enable input. ENB turns on or off low dropout regulator B (LDO B). Drive ENB high to turn on LDO B; drive it low to turn it off. |
| 16 | C2+ | Positive node of charge pump capacitor 2. Connect the 1µF charge pump capacitor 2 from C2+ to C2-. |
| 17 | C2- | Negative node of charge pump capacitor 2. Connect the 1µF charge pump capacitor 2 from C2+ to C2-. |
| 19 | PGND | Power ground. Connect AGND to PGND at a single point as close to the AAT2856 as possible. |
| 20 | ENS | Backlight enable and serial control input. ENS turns the backlight on/off and is the AS ² Cwire input to serially control the backlightLED brightness. |
| 25 | BL6 | Backlight LED 6 current sink. BL6 controls the current through backlight LED 6. Connect the cathode of backlight LED 6 to BL6. If not used, connect BL6 to OUT. |
| 26 | BL5 | Backlight LED 5 current sink. BL5 controls the current through backlight LED 5. Connect the cathode of backlight LED 5 to BL5. If not used, connect BL5 to OUT. |
| 27 | ENA | LDO A enable input. ENA turns on or off low dropout regulator A (LDO A). Drive ENA high to turn on LDO A; drive low to turn it off. |
| 28 | BL4 | Backlight LED 4 current sink. BL4 controls the current through backlight LED 4. Connect the cathode of backlight LED 4 to BL4. If not used, connect BL4 to OUT. |
| EP | | Exposed paddle (bottom); connect to ground as closely as possible to the device. |

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications

Pin Configuration

**TQFN44-28
(Top View)**


Absolute Maximum Ratings¹

| Symbol | Description | Value | Units |
|------------|---|-------------------------|-------|
| | IN, OUT, BL1, BL2, BL3, BL4, BL5, BL6 Voltage to AGND | -0.3 to 6.0 | V |
| | C1+, C1-, C2+, C2- Voltage to AGND | -0.3 to $V_{OUT} + 0.3$ | V |
| | REF, FBB, OUTA, FBA, OUTB, ENA, ENS Voltage to AGND | -0.3 to $V_{IN} + 0.3$ | V |
| | PGND Voltage to AGND | -0.3 to 0.3 | V |
| T_J | Operating Junction Temperature Range | -40 to 150 | °C |
| T_{LEAD} | Maximum Soldering Temperature (at leads, 10 sec) | 300 | °C |

Thermal Information²

| Symbol | Description | Value | Units |
|---------------|--|-------|-------|
| P_D | Maximum Power Dissipation ³ | 2 | W |
| θ_{JA} | Maximum Thermal Resistance | 50 | °C/W |

1. Stresses above those listed in Absolute Maximum Ratings may cause permanent damage to the device. Functional operation at conditions other than the operating conditions specified is not implied. Only one Absolute Maximum Rating should be applied at any one time.
 2. Mounted on a FR4 circuit board.
 3. Derate 6.25 mW/°C above 25°C ambient temperature.

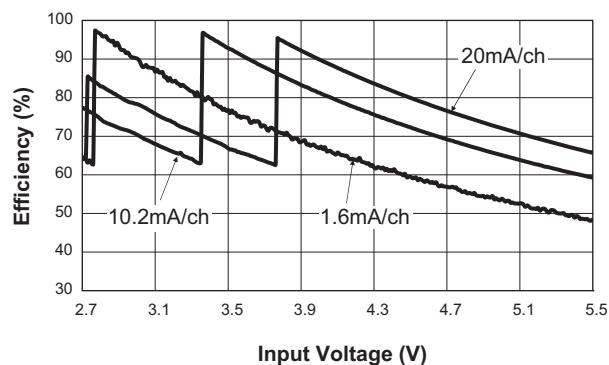
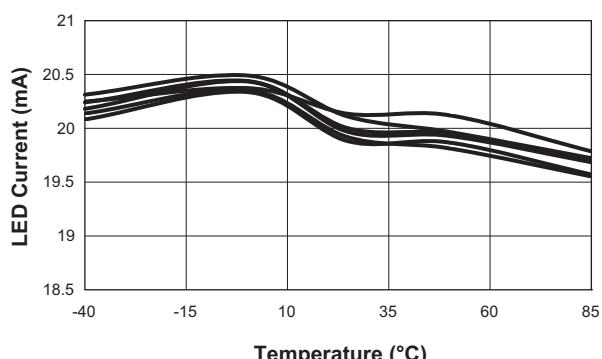
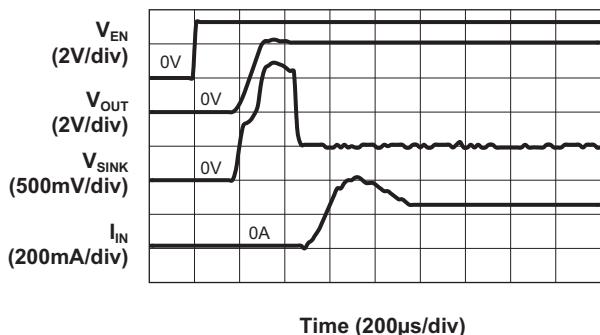
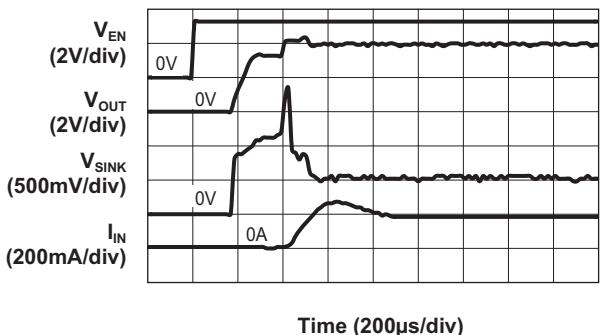
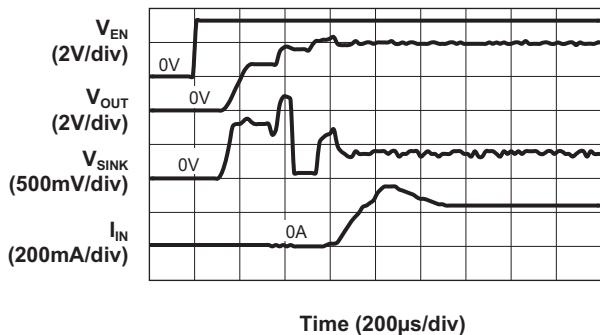
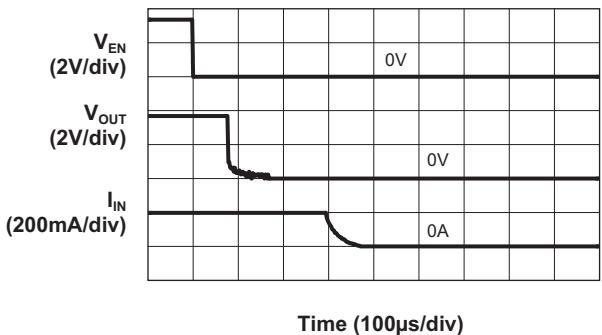
ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Electrical Characteristics¹

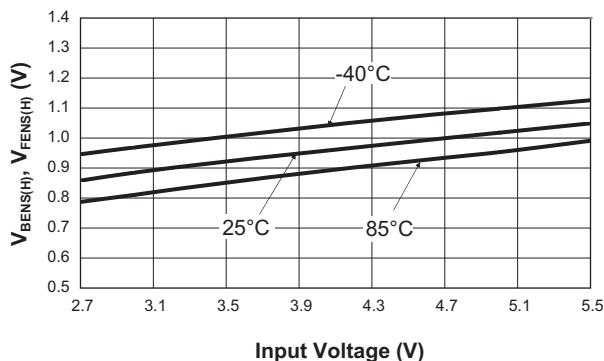
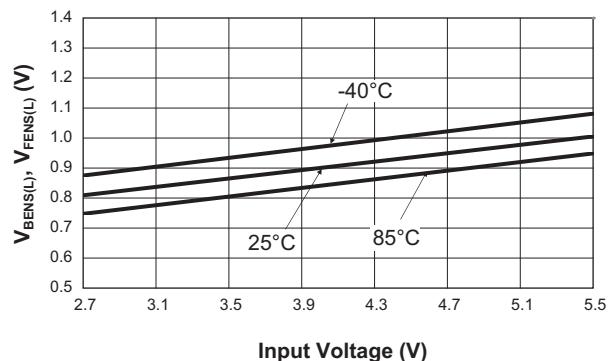
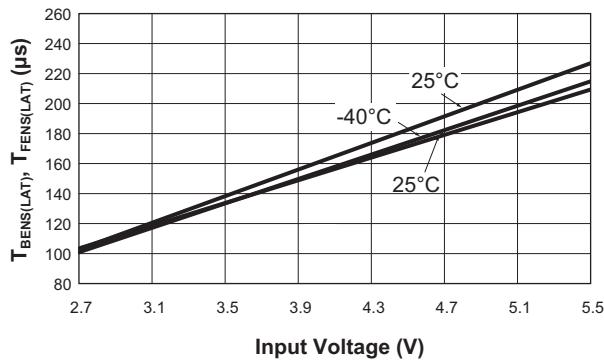
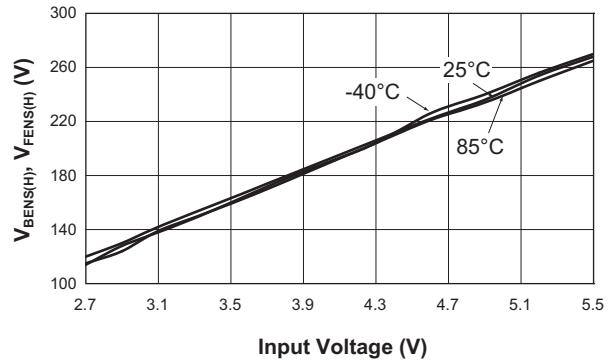
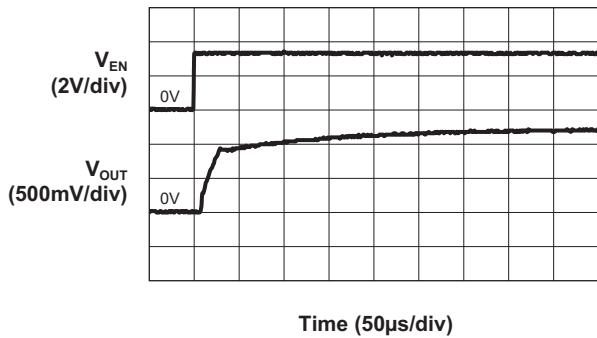
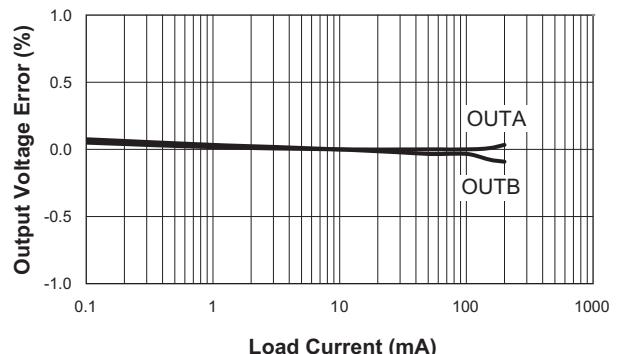
$V_{IN} = 3.6V$; $C_{IN} = 4.7\mu F$; $C_{OUT} = 2.2\mu F$; $C_1 = C_2 = 1\mu F$; $T_A = -40^{\circ}C$ to $+85^{\circ}C$, unless otherwise noted. Typical values are $T_A = 25^{\circ}C$.

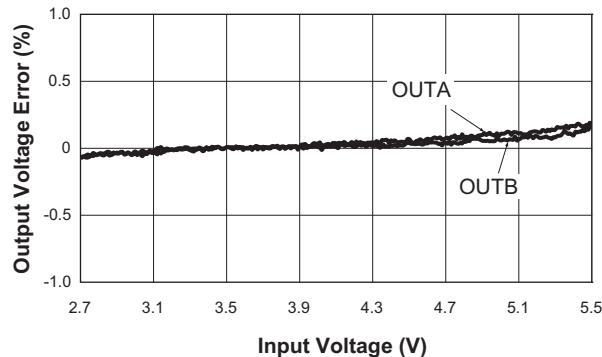
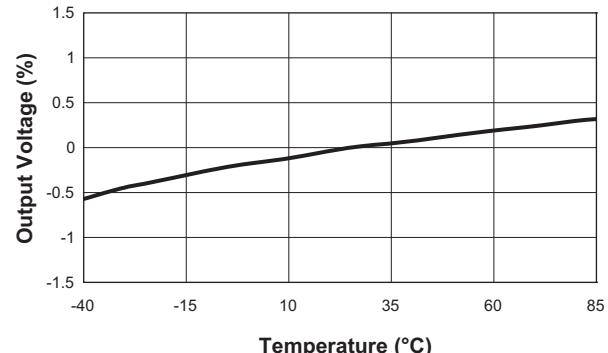
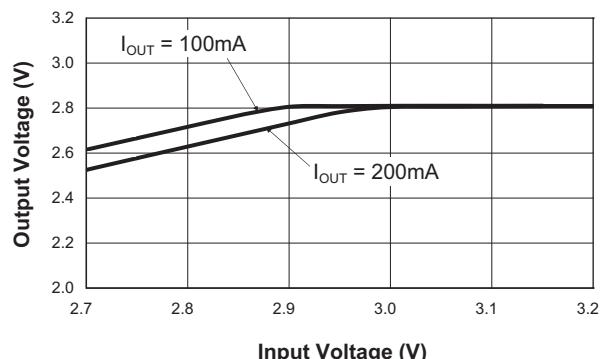
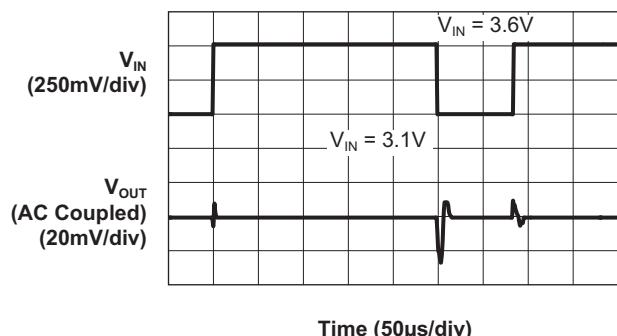
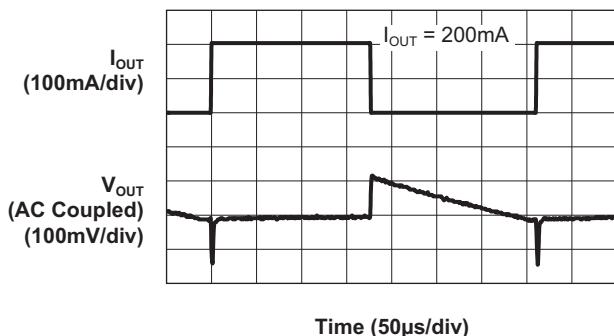
| Symbol | Description | Conditions | Min | Typ | Max | Units |
|--------------------------------------|---|---|------|------|------|-------------|
| V_{IN} | IN Operating Voltage Range | | 2.7 | | 5.5 | V |
| $I_{IN(Q)}$ | IN Operating Current | 1X Mode, $3.0V \leq V_{IN} \leq 5.5V$, Active, No Load; ENL = AGND, ENS = IN | | 0.63 | 1 | mA |
| | | 1.5X Mode, $3.0V \leq V_{IN} \leq 5.5V$, Active, No Load; ENL = AGND, ENS = IN | | 1.4 | 4 | |
| | | 2X Mode, $3.0V \leq V_{IN} \leq 5.5V$, Active, No Load; ENL = AGND, ENS = IN | | 2.6 | 5 | |
| $I_{IN(SHDN)}$ | IN Shutdown Current | ENA = ENB = ENS = AGND | | | 1.0 | μA |
| T_{SD} | Over-Temperature Shutdown Threshold | | | 140 | | $^{\circ}C$ |
| $T_{SD(HYS)}$ | Over-Temperature Shutdown Hysteresis | | | 15 | | $^{\circ}C$ |
| Charge Pump Section | | | | | | |
| I_{OUT} | OUT Maximum Output Current | | | 200 | | mA |
| $V_{IN(TH_H)}$ | Charge Pump Mode Hysteresis | Address 0, Data 1 | | 500 | | mV |
| f_{OSC} | Charge Pump Oscillator Frequency | $T_A = 25^{\circ}C$ | | 2 | | MHz |
| BL1-BL6 Backlight LED Outputs | | | | | | |
| $I_{BL_}(MAX)$ | BL1-BL6 Maximum Current | Address 0, Data 1; $V_{IN} - V_F = 1.5V$ | 18 | 20 | 22 | mA |
| | | Address 12, Data 2; $V_{IN} - V_F = 1.5V$ | | 30 | | |
| $\Delta I_{(BL_)}$ | BL1-BL6 Current Matching ² | Address 0, Data 1; $V_{IN} - V_F = 1.5V$ | | | 1.0 | % |
| $V_{BL_}(TH)$ | BL1-BL6 Charge Pump Mode Transition Threshold | | | 150 | | mV |
| ENS Logic Control | | | | | | |
| $V_{ENS(L)}$ | ENS Input Low Threshold | | | | 0.4 | V |
| $V_{ENS(H)}$ | ENS Input High Threshold | | 1.4 | | | V |
| I_{ENS} | ENS Input Leakage Current | $V_{ENS} = V_{IN} = 5V$ | -1.0 | | 1.0 | μA |
| $t_{ENS(LOW)}$ | ENS Serial Interface Low Time | $V_{IN} \geq 3.3V$ | 0.3 | | 75 | μs |
| $t_{ENS(HI_MIN)}/t_{ENS(HI_MIN)}$ | ENS Serial Interface Minimum High Time | | | 50 | | ns |
| $t_{ENS(HI_MAX)}/t_{ENS(HI_MAX)}$ | ENS Serial Interface Maximum High Time | $V_{IN} \geq 3.3V$ | | | 75 | μs |
| $t_{ENS(OFF)}$ | ENS Off Timeout | | | | 500 | μs |
| $t_{ENS(LAT)}$ | ENS Serial Interface Latch Timeout | | | | 500 | μs |
| Linear Regulators | | | | | | |
| V_{FBA}, V_{FBB} | Output Voltage Tolerance | $I_{OUT} = 1mA$ to $200mA$ | 1.17 | 1.2 | 1.23 | V |
| | | ENA = ENB = IN, ENS = AGND | | 125 | 200 | |
| I_{IN} | Ground Pin Current | ENA = IN, ENB = AGND or ENA = AGND, ENB = IN, ENS = AGND | | 90 | 150 | μA |
| $I_{OUTA(MAX)}, I_{OUTB(MAX)}$ | OUTA, OUTB Maximum Load Current | | 200 | | | mA |
| $V_{OUTA(DO)}, V_{OUTB(DO)}$ | OUTA, OUTB Dropout Voltage | $I_{OUT} = 150mA$ | | 150 | 300 | mV |
| $PSRR_A, PSRR_B$ | OUTA, OUTB Power Supply Rejection Ratio | $I_{OUT} = 10mA$, $C_{REF} = 10nF$, $1kHz$ | | 50 | | dB |
| V_{EN_L} | ENA, ENB Voltage Low Threshold | | | | 0.4 | V |
| V_{EN_H} | ENA, ENB Voltage High Threshold | | 1.4 | | | V |
| t_{EN_DLY} | ENA, ENB Enable Delay | REF = Open | | 15 | | μs |

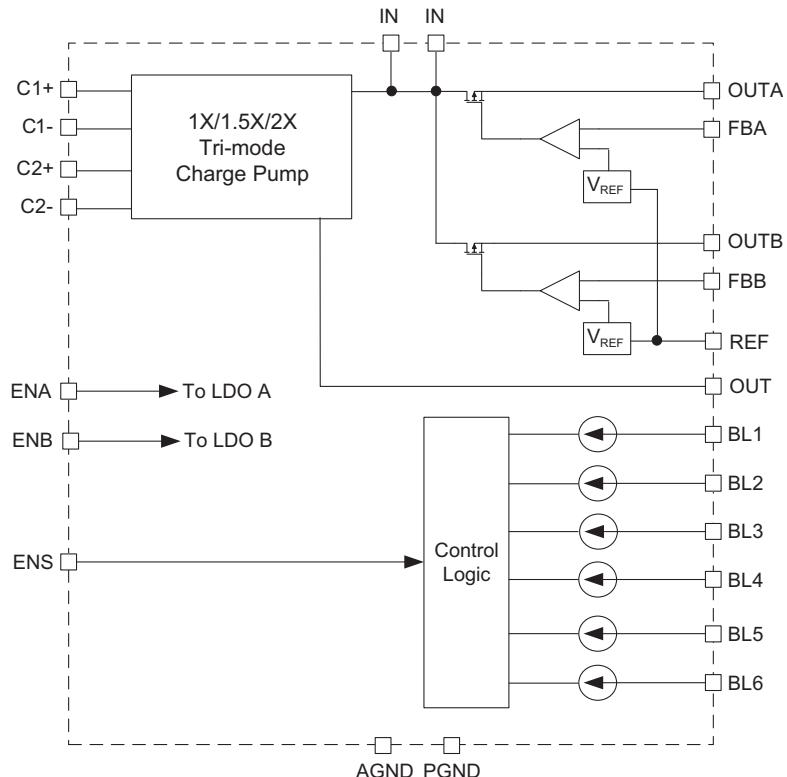
1. The AAT2856 is guaranteed to meet performance specifications over the $-40^{\circ}C$ to $+85^{\circ}C$ operating temperature range and is assured by design, characterization, and correlation with statistical process controls.

2. Current matching is defined as the deviation of any sink current from the average of all active channels.

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Typical Characteristics
Backlight Efficiency vs. Input Voltage

**Backlight Current Matching vs. Temperature
(20mA/Ch; Data 1)**

**Turn On to 1X Mode Backlight
(30mA/ch; Data 1; V_{IN} = 4.2V)**

**Turn On to 1.5X Mode Backlight
(30mA/ch; Data 1; V_{IN} = 3.4V)**

**Turn On to 2X Mode Backlight
(30mA/ch; Data 1; V_{IN} = 2.7V)**

**Turn Off from 1.5X Mode Backlight
(30mA/ch; Data 1)**


ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Typical Characteristics
**BENS, FENS High Threshold Voltage
vs. Input Voltage**

**BENS, FENS Low Threshold Voltage
vs. Input Voltage**

BENS, FENS Latch Timeout vs. Input Voltage

BENS, FENS Off Timeout vs. Input Voltage

LDOs A and B Turn On Characteristic

LDOs A and B Load Regulation


ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Typical Characteristics
LDOs A and B Line Regulation

LDOs A and B Output Voltage vs. Temperature

LDOs A and B Dropout Characteristics

LDOs A and B Line Transient Response (10mA Load)

LDOs A and B Load Transient Response (10mA to 200mA Load Step)


ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Functional Block Diagram

Functional Description

The AAT2856 is a highly integrated backlight LED driver with two LDO linear regulators. The charge pump LED driver drives backlight LEDs from a 2.7V to 5.5V input voltage. The LDO regulators are operated from the same input voltage range and produce regulated output voltages as low as 1.2V.

LED Drivers

The LEDs are driven from an internal charge pump that, depending on the battery voltage and LED forward voltage, drives LEDs directly from the supply voltage (1X or bypass mode) or steps up the supply voltage by a factor of 1.5 (1.5X mode) or 2 (2X mode). The charge pump requires only two tiny 1 μ F ceramic capacitors, providing a more compact solution than typical inductor-based step-up converter solutions. Each individual LED is driven by a current sink to AGND, allowing individual current control with high accuracy over a wide range of input voltages and LED forward voltages while maintaining high efficiency.

The charge pump is controlled by the voltage across the LED current sinks. When any one of the active current sinks begins to dropout, the charge pump goes to the next higher mode (from 1X to 1.5X or from 1.5X to 2X mode) to maintain sufficient LED voltage for constant LED current. The AAT2856 continuously monitors the LED forward voltages and uses the input voltage to determine when to reduce the charge pump mode for better efficiency. There is also a 500mV mode-transition hysteresis that prevents the charge pump from oscillating between charge pump modes.

The backlight LED current levels are dynamically controllable by the AS²Cwire single-wire interface. The backlight section has multiple current level scales and the maximum current level is fixed at 20mA or 30mA, depending on the scale chosen through programming.

If any one of the backlight or flash current sinks is not used, connect that current sink to OUT. The current controller monitors the sink voltage and, if it is connected to OUT, then the controller determines that the current sink is not used or that the LED is shorted. In either case, the controller turns off the affected current sink.

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications

AS²Cwire Serial Interface

The AAT2856 is dynamically programmable by the AS²Cwire single-wire interface. AS²Cwire records rising edges detected at the ENS pin to address and load the data registers. AS²Cwire latches data or address after the ENS input has been held high for time t_{LAT} (500 μ s). Address or data is differentiated by the number of ENS rising edges. Since the data registers are 4 bits each, the differentiating number of pulses is 24 or 16, so that Address 0 is identified by 17 rising edges, Address 1 by 18 rising edges, Address 2 by 19 rising edges, etc. Data is set to any number of rising edges between 1 and 16. A typical write protocol is a burst of ENS rising edges identifying a particular address, followed by a pause with ENS held high for the t_{LAT} timeout period, then a burst of rising edges signifying data, and another t_{LAT} timeout after the data has been sent. Once an address is set, multiple writes to that address are allowed since the address is not reset after each write. Address edges are needed when changing the address, or writing to an address other than the default after shutdown. Address 0 is the default address after shutdown. If the part is enabled with only data edges and no address, then Address 0 will be programmed and backlight channels BL1-BL6 will turn-on according to the number of data edges applied.

When ENS is held low for a time longer than t_{OFF} (500 μ s), the AAT2856 enters shutdown mode and draws less than 1 μ A of current from IN. At shutdown, the data and address registers are reset to 0.

Table 1a contains the AS²Cwire serial interface address functionality when independent channel control is disabled (independent channel control is disabled by default) and conversely Table 1b contains the AS²Cwire serial interface address functionality when independent channel control is enabled.

AS²Cwire Serial Interface Addressing

| Address | ENS Rising Edges | Function |
|---------|------------------|---|
| 0 | 17 | Backlight Current BL1-BL6 |
| 1 | 18 | Main Backlight Current BL1-BL5 |
| 2 | 19 | Sub Backlight Current BL6 |
| 3 | 20 | Low Current Backlight |
| 12 | 29 | Maximum Backlight Current Scale BL1-BL6 |
| 15 | 32 | Backlight Independent Channel Control |

Table 1a: AS²Cwire Serial Interface Addressing with Independent Channel Control Disabled.

| Address | ENS Rising Edges | Function |
|---------|------------------|---|
| 0 | 17 | Not Applicable |
| 1 | 18 | Backlight Current BL1-BL6 |
| 2 | 19 | BL3-BL6 On/Off Control |
| 3 | 20 | BL1-BL2 On/Off Control |
| 12 | 29 | Maximum Backlight Current Scale BL1-BL6 |
| 15 | 32 | Not Applicable |

Table 1b: AS²Cwire Serial Interface Addressing with Independent Channel Control Enabled.

Backlight Current Control (Address 0-3)

Use Addresses 0-3 to program all six backlight LED channels. All six backlight channels are programmed to the same current level by writing Address 0 followed by any Data between 1 and 16. To program only the main channels BL1 through BL5, use Address 1. Similarly, use Address 2 to program only the sub channel BL6 independently.

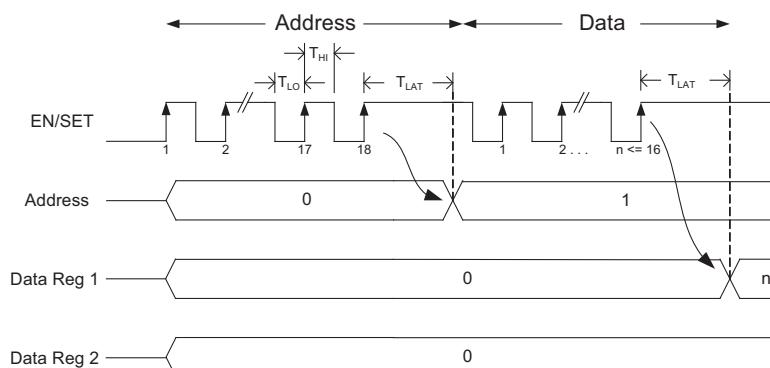


Figure 1: AS²Cwire Serial Interface Timing.

ChargePump™ High Current Charge Pump with Dual LDO for Backlight Applications

The AAT2856 incorporates additional circuitry that optimizes performance for exceptionally low backlight current settings. A separate address is used to activate this circuitry. To program the low current settings with improved performance and efficiency, write to Address 3. Unlike Addresses 0-2, which have current level settings according to Table 2 and Figure 2, Address 3 possesses a separate set of current levels described by the Low Current Backlight settings found in Table 3.

| Data | 30mA Max (mA) | 20mA Max (mA) |
|------|---------------|---------------|
| 1 | 30.0 | 20.0 |
| 2 | 27.9 | 19.0 |
| 3 | 26.1 | 17.8 |
| 4 | 24.2 | 16.5 |
| 5 | 21.0 | 14.3 |
| 6 | 19.2 | 13.0 |
| 7 | 17.3 | 11.8 |
| 8 | 15.0 | 10.2 |
| 9 | 12.7 | 8.5 |
| 10 | 10.9 | 7.3 |
| 11 | 8.1 | 5.4 |
| 12 | 6.2 | 4.1 |
| 13 | 4.4 | 2.9 |
| 14 | 3.5 | 2.2 |
| 15 | 2.6 | 1.6 |
| 16 | 0 | 0 |

Table 2: Data for the Backlight Current Level, Addresses 0-3.

| Data | Main Current On | Sub Current On | Current (μA) |
|------|-----------------|----------------|--------------|
| 1 | No | No | 0 |
| 2 | No | No | 0 |
| 3 | No | No | 0 |
| 4 | No | No | 0 |
| 5 | No | Yes | 95 |
| 6 | No | Yes | 500 |
| 7 | No | Yes | 950 |
| 8 | No | Yes | 1900 |
| 9 | Yes | No | 95 |
| 10 | Yes | No | 500 |
| 11 | Yes | No | 950 |
| 12 | Yes | No | 1900 |
| 13 | Yes | Yes | 95 |
| 14 | Yes | Yes | 500 |
| 15 | Yes | Yes | 950 |
| 16 | Yes | Yes | 1900 |

Table 3: Low-Level Backlight Current, Address 3, FS = 20mA Range.

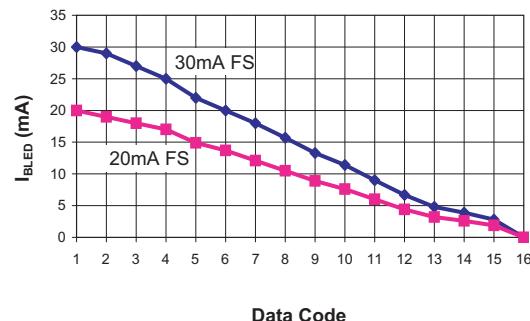


Figure 2: Data Code for Address 0-3 vs. Backlight Current Level.

Maximum Backlight Current (Address 12)

There are two separate current level scales that apply to Addresses 0-2: 20mA and 30mA. According to the Maximum Backlight Current setting at Address 12, only one of the two scales can be active at any given time and never both. By default, the 20mA scale is active on startup. To change to the 30mA scale, or go back to the 20mA scale, write to Address 12.

Since only one of the scales can be active at any given time, the 20mA and 30mA scales cannot be mixed between main and sub. When setting Address 12 to the 30mA scale, only current levels from that scale can be mixed between main and sub. When changing maximum current scales, the data remains constant regardless of scale. When the maximum current scale is changed, the previously stored data value will remain constant but the current value will change due to the different current values on the separate maximum current scales.

| Data | Maximum Current Scale |
|------|-----------------------|
| 1 | 20mA |
| 2 | 30mA |

Table 4: Address 12 Maximum Current Scale.

Backlight Independent Channel Control (Address 15)

The AAT2856 has a unique independent channel control mode whereby individual backlight LED channels can be enabled and disabled to form a custom arrangement of active channels.

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications

To enable independent channel control mode, write Data 8 to Address 15. To exit individual mode control, the AAT2856 state machine can be reset by strobing ENS low and holding ENS low longer than the AS²Cwire's t_{OFF} latch time.

| Data | Individual Backlight Control |
|------|------------------------------|
| 8 | On |

Table 5: Address 15, Independent Backlight Control.

With independent channel control enabled, the functionality of Addresses 2 and 3 will conform to what is described in Tables 8 and 9. Also Address 0 is no longer applicable after independent channel control has been enabled. As indicated by the possible settings listed in the tables, any combination of backlight channels can be enabled and disabled. The original functionality (Sub Backlight Current BL6 and Low Current Backlight) of Addresses 2 and 3 are no longer available unless the internal state machine has been reset to default mode operation (when ENS is logic low for $>500\mu s$). The functionality of the maximum backlight current scale (Address 12) is unmodified by the enabling of independent channel control.

The LDO enables are always independent of AS²Cwire programming.

| Data | BL6 | BL5 | BL4 | BL3 |
|------|-----|-----|-----|-----|
| 1 | Off | Off | Off | Off |
| 2 | Off | Off | Off | On |
| 3 | Off | Off | On | Off |
| 4 | Off | Off | On | On |
| 5 | Off | On | Off | Off |
| 6 | Off | On | Off | On |
| 7 | Off | On | On | Off |
| 8 | Off | On | On | On |
| 9 | On | Off | Off | Off |
| 10 | On | Off | Off | On |
| 11 | On | Off | On | Off |
| 12 | On | Off | On | On |
| 13 | On | On | Off | Off |
| 14 | On | On | Off | On |
| 15 | On | On | On | Off |
| 16 | On | On | On | On |

Table 6: Address 2 with Independent Channel Control Enabled: BL3-BL6 On/Off Control.

| Data | BL2 | BL1 |
|------|-----|-----|
| 1 | Off | Off |
| 2 | Off | Off |
| 3 | Off | Off |
| 4 | Off | Off |
| 5 | Off | On |
| 6 | Off | On |
| 7 | Off | On |
| 8 | Off | On |
| 9 | On | Off |
| 10 | On | Off |
| 11 | On | Off |
| 12 | On | Off |
| 13 | On | On |
| 14 | On | On |
| 15 | On | On |
| 16 | On | On |

Table 7: Address 3 with Independent Channel Control Enabled: BL1 and BL2 On/Off Control.

Low Dropout Regulators

The AAT2856 includes two independent LDO linear regulators. The regulators operate from a 2.7V to 5.5V input voltage at IN. The AAT2856 supplies separate LDO enable inputs (ENA and ENB) to control individually the operation of the LDOs. The LDO output voltages are set through resistive voltage dividers from the output (OUTA or OUTB) to the feedback input (FBA or FBB). The regulator controls the output voltage such that the voltage divider output is at the 1.2V feedback threshold. The low 200mV dropout voltage at 200mA load current allows the regulator to maintain output voltage regulation.

Each LDO regulator can supply up to 200mA continuous current to the load. They include current limiting and thermal overload protection to prevent damage to the load or to the LDOs.

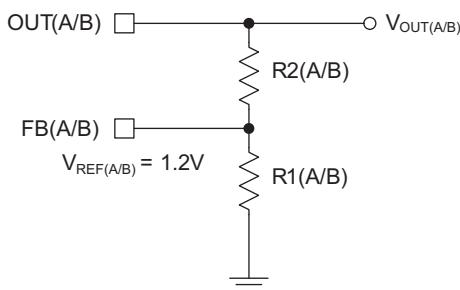
ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications

Applications Information

LDO Output Voltage Programming

The output voltages for LDOA and LDOB are programmed by an external resistor divider network. As shown below, the selection of R_1 and R_2 is a straight forward matter.

R_1 is chosen by considering the tradeoff between the feedback network bias current and resistor value. Higher resistor values allow stray capacitance to become a larger factor in circuit performance whereas lower resistor values increase bias current and decrease efficiency.



To select appropriate resistor values, first choose R_1 such that the feedback network bias current is less than $10\mu\text{A}$. Then, according to the desired V_{OUT} , calculate R_2 according to the equation below. An example calculation follows.

An R_1 value of 120K is chosen, resulting in a small feedback network bias current of $1.2\text{V}/120\text{K} = 10\mu\text{A}$. The desired output voltage is 1.8V . From this information, R_2 is calculated from the equation below.

$$R_2 = \frac{R_1(V_{\text{OUT}} - 1.2\text{V})}{1.2\text{V}}$$

The result is $R_2 = 60\text{K}$. Since 60K is not a standard 1%-value, 60.4K is selected. From this example calculation, for $V_{\text{OUT}} = 1.8\text{V}$, use $R_1 = 120\text{K}$ and $R_2 = 60.4\text{K}$. Example output voltages and corresponding resistor values are provided in Table 8.

Selection of set resistor values outside of the typical application must be carefully evaluated to ensure that the application's performance requirements can still be met.

| R ₂ Standard 1% Values (R ₁ = 120K) | |
|---|--------------------|
| V _{OUT} (V) | R ₂ (Ω) |
| 2.8 | 160K |
| 2.5 | 130K |
| 2.0 | 79.6K |
| 1.8 | 60.4K |
| 1.5 | 30.1K |

Table 8: Example Output Voltages and Corresponding Resistor Values.

Device Power Efficiency

The AAT2856 power conversion efficiency depends on the charge pump mode. By definition, device efficiency is expressed as the output power delivered to the LEDs divided by the total input power consumed.

$$\eta = \frac{P_{\text{OUT}}}{P_{\text{IN}}}$$

When the input voltage is sufficiently greater than the LED forward voltages, the device optimizes efficiency by operating in 1X mode. In 1X mode, the device is working as a bypass switch and passing the input supply directly to the output. By simplifying the conditions such that the LEDs have uniform V_F , the power conversion efficiency can be approximated by:

$$\eta = \frac{V_F \cdot I_{\text{LED}}}{V_{\text{IN}} \cdot I_{\text{IN}}} \approx \frac{V_F}{V_{\text{IN}}}$$

Due to the very low 1X mode quiescent current, the input current nearly equals the total output current delivered to the LEDs. Further, the low-resistance bypass switch introduces negligible voltage drop from input to output.

The AAT2856 further maintains optimized performance and efficiency by detecting when the input voltage is not sufficient to sustain LED drive current. The device automatically switches to 1.5X mode when the input voltage drops too low in relation to the LED forward voltages.

In 1.5X mode, the output voltage can be boosted to $3/2$ the input voltage. The $3/2$ conversion ratio introduces a corresponding $1/2$ increase in input current. For ideal conversion, the 1.5X mode efficiency is given by:

$$\eta = \frac{V_F \cdot I_{\text{LED}}}{V_{\text{IN}} \cdot 1.5I_{\text{IN}}} = \frac{V_F}{1.5 \cdot V_{\text{IN}}}$$

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications

Similarly, when the input falls further, such that 1.5X mode can no longer sustain LED drive current, the device will automatically switch to 2X mode. In 2X mode, the output voltage can be boosted to twice the input voltage. The doubling conversion ratio introduces a corresponding doubling of the input current. For ideal conversion, the 2X mode efficiency is given by:

$$\eta = \frac{V_F \cdot I_{LED}}{V_{IN} \cdot 2I_{IN}} = \frac{V_F}{2 \cdot V_{IN}}$$

LED Selection

The AAT2856 is designed to drive high-intensity white LEDs. It is particularly suitable for LEDs with an operating forward voltage in the range of 1.5V to 4.2V.

The charge pump can also drive other loads that have similar characteristics to white LEDs. For various load types, the AAT2856 provides a high-current, programmable ideal constant current source.

Capacitor Selection

Careful selection of the four external capacitors C_{IN} , C_1 , C_2 , and C_{OUT} is important because they will affect turn-on time, output ripple, and transient performance. Optimum performance will be obtained when low equivalent series resistance (ESR) ceramic capacitors are used. In general, low ESR may be defined as less than 100m Ω .

Ceramic composition capacitors are highly recommended over all other types of capacitors for use with the AAT2856. Ceramic capacitors offer many advantages over their tantalum and aluminum electrolytic counterparts. A ceramic capacitor typically has very low ESR, is lowest cost, has a smaller PCB footprint, and is non-polarized. Low ESR ceramic capacitors help maximize charge pump transient response. Since ceramic capacitors are non-polarized, they are not prone to incorrect connection damage.

Equivalent Series Resistance

ESR is an important characteristic to consider when selecting a capacitor. ESR is a resistance internal to a capacitor that is caused by the leads, internal connections, size or area, material composition, and ambient temperature. Capacitor ESR is typically measured in milliohms for ceramic capacitors and can range to more than several ohms for tantalum or aluminum electrolytic capacitors.

Ceramic Capacitor Materials

Ceramic capacitors less than 0.1 μ F are typically made from NPO or C0G materials. NPO and C0G materials generally have tight tolerance and are very stable over temperature. Larger capacitor values are usually composed of X7R, X5R, Z5U, or Y5V dielectric materials. Large ceramic capacitors are often available in lower-cost dielectrics, but capacitors greater than 10 μ F are not typically required for AAT2856 applications.

Capacitor area is another contributor to ESR. Capacitors that are physically larger will have a lower ESR when compared to an equivalent material smaller capacitor. These larger devices can improve circuit performance when compared to an equal value capacitor in a smaller package size.

PCB Layout

To achieve adequate electrical and thermal performance, careful attention must be given to the PCB layout. In the worst-case operating condition, the chip must dissipate considerable power at full load. Adequate heat-sinking must be achieved to ensure intended operation.

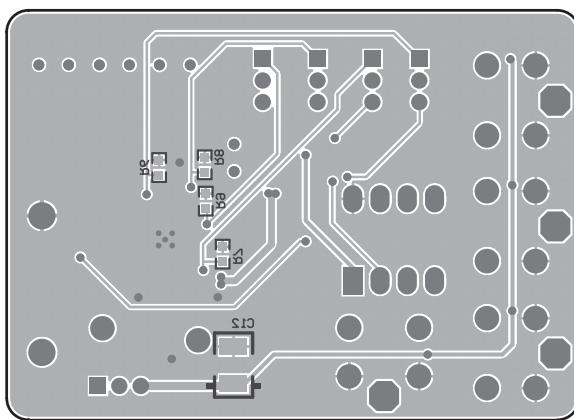
Figure 3 illustrates an example PCB layout. The bottom of the package features an exposed metal paddle. The exposed paddle acts, thermally, to transfer heat from the chip and, electrically, as a ground connection.

The junction-to-ambient thermal resistance (θ_{JA}) for the connection can be significantly reduced by following a couple of important PCB design guidelines.

The PCB area directly underneath the package should be plated so that the exposed paddle can be mated to the top layer PCB copper during the re-flow process. Multiple copper plated thru-holes should be used to electrically and thermally connect the top surface paddle area to additional ground plane(s) and/or the bottom layer ground pour.

The chip ground is internally connected to both the paddle and to the AGND and PGND pins. It is good practice to connect the GND pins to the exposed paddle area with traces as shown in the example.

The flying capacitors C_1 and C_2 should be connected close to the IC. Trace length should be kept short to minimize path resistance and potential coupling. The input and output capacitors should also be placed as close to the chip as possible.

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Figure 3: Example PCB Layout.
Evaluation Board User Interface

The user interface for the AAT2856 evaluation board is provided through 4 buttons and a number of connection terminals. The board is operated by supplying external power and pressing individual buttons or button combinations. The table below indicates the function of each button or button combination.

To power-on the board, connect a power supply or battery to the DC- and DC+ terminals. Make the board's

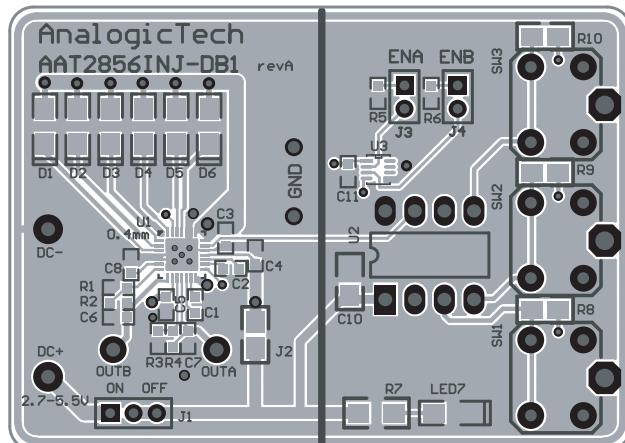
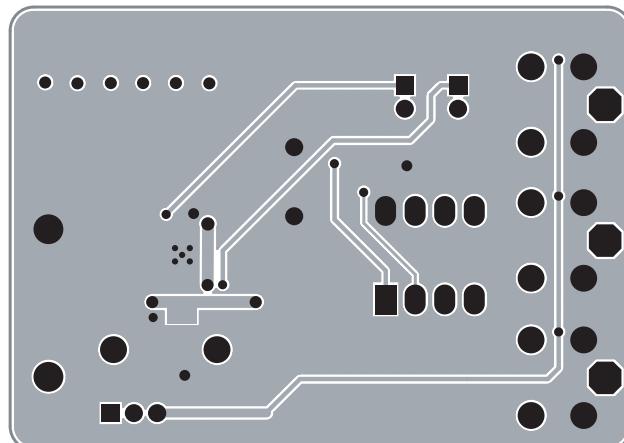
supply connection by positioning the J1 jumper to the ON position. A red LED indicates that power is applied.

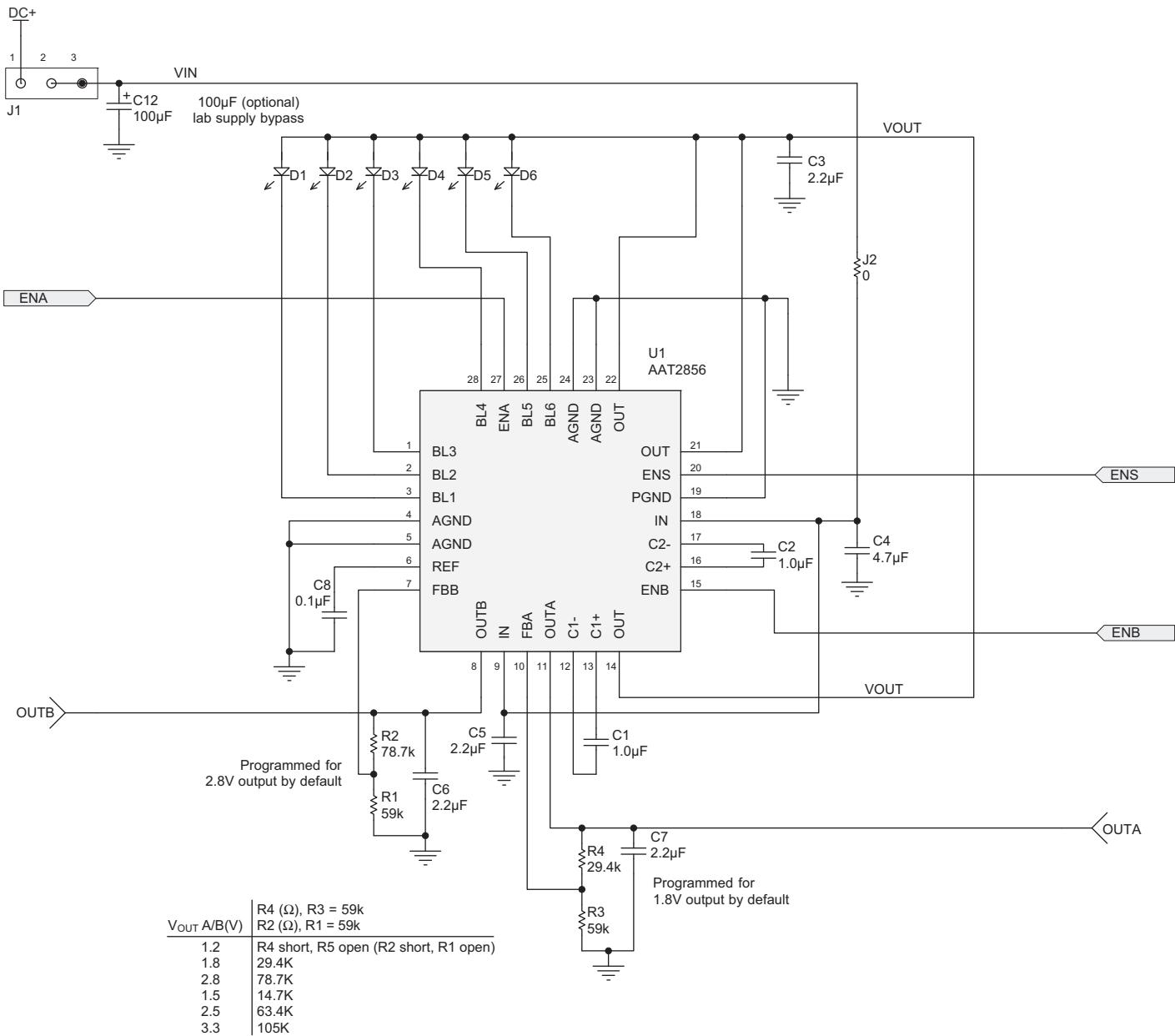
The Enables of both LDOs are connected with jumpers J3 and J4. These terminals must be connected to the external source to turn on/off the LDOs.

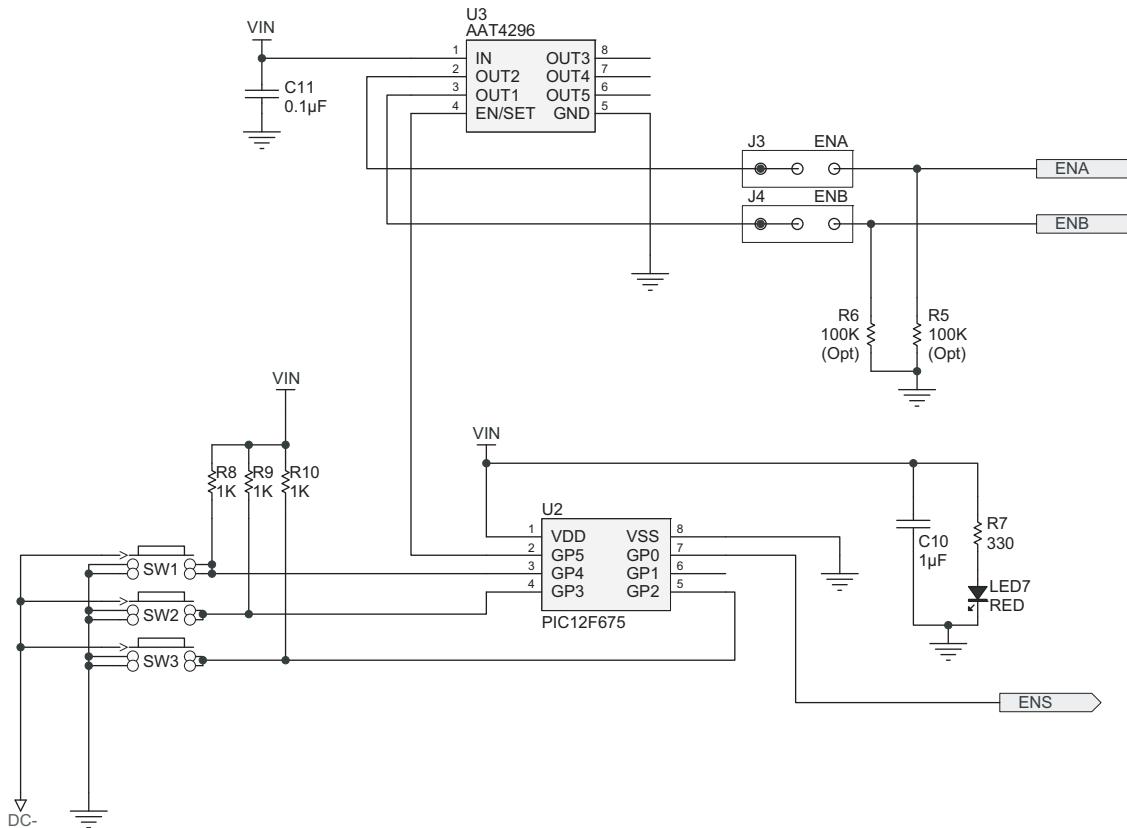
When applying external enable signals, consideration must be given to the voltage levels. The externally applied voltages cannot exceed the supply voltage that is applied to the IN pins of the device (DC+).

The LDO loads can be connected directly to the evaluation board. For adequate performance, be sure to connect the load between OUTA/OUTB and DC- as opposed to some other GND in the system.

| Button(s) Pushed | Description |
|---------------------|---|
| SW1 | [Push/Release once] Increment the number of EN/SET edges, but the backlight current is decreased (dimmer). If held down, auto-cycle through the settings. |
| SW2 | [Push/Release once] Decrement the number of EN/SET edges, but the backlight current is increased (brighter). If held down, auto-cycle through the settings. |
| SW3 | [Push/Release once] Toggle between 20mA and 30mA maximum current. |

Table 9: AAT2856 Evaluation Board User Interface¹.
Evaluation Board Layout

Figure 4: AAT2856 Evaluation Board Layout Top Side.

Figure 5: AAT2856 Evaluation Board Layout Bottom Side.
¹. The enable for LDOA and LDOB are manually set externally.

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Evaluation Board Schematics

Figure 6: AAT2856 Section Schematic.

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Figure 7: MCU and I/O Expander Section Schematic.
Evaluation Board Component Listing

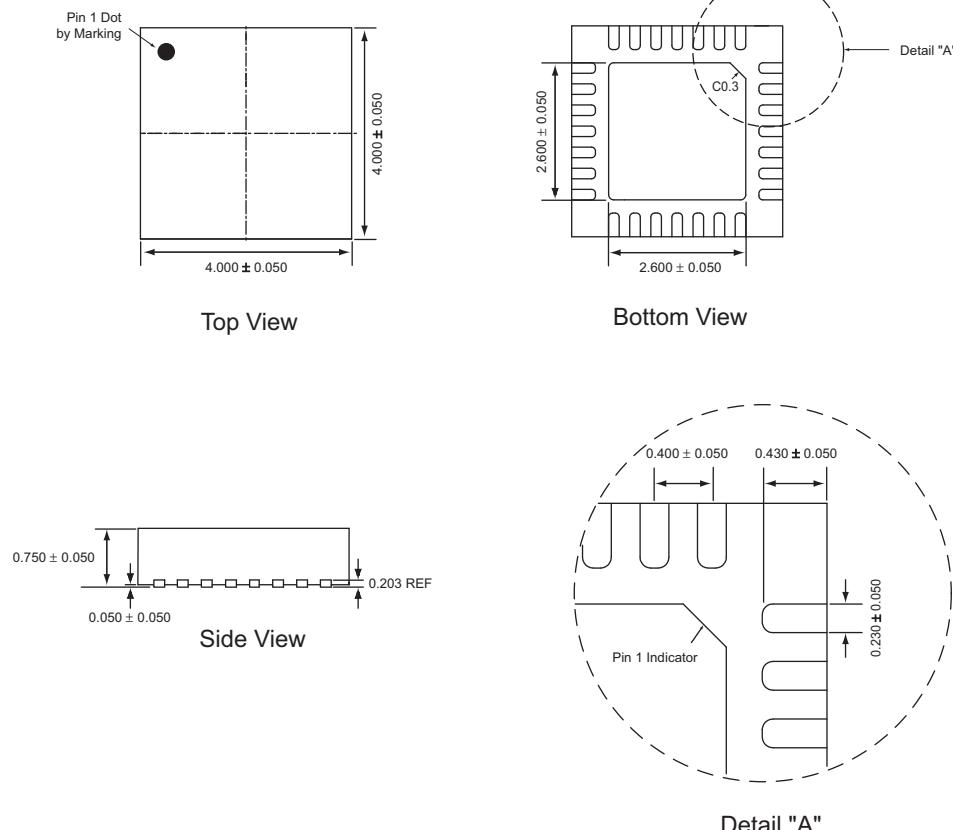
| Component | Part# | Description | Manufacturer |
|----------------|------------------|---|------------------------|
| U1 | AAT2856INJ-EE-T1 | High Eff. 1X/1.5X/2X CP for White LED, Dual LDO | AnalogicTech |
| U2 | PIC12F675 | 8-bit CMOS, FLASH MCU; 8-pin PDIP | Microchip |
| U3 | AAT4296IJS-1-T1 | I/O Expander | AnalogicTech |
| D1-D6 | LW M673 | Mini TOLED White LED; SMT | OSRAM |
| C1, C2, C10 | GRM18x | 1.0µF, 10V, X5R, 0603, Ceramic | Murata |
| C3, C5, C6, C7 | GRM18x | 2.2µF, 10V, X5R, 0603, Ceramic | Murata |
| C4 | GRM18x | 4.7µF, 10V, X5R, 0603, Ceramic | Murata |
| C8, C11 | GRM18x | 0.1µF, 16V, X7R, 0603, Ceramic | Murata |
| C12 | TAJBx | 100µF, 10V, 10µA, Tantalum | AVX |
| R8-R10 | Chip Resistor | 1K, 5%, 1/4W; 1206 | Vishay |
| R7 | Chip Resistor | 330, 5%, 1/4W; 1206 | Vishay |
| R5, R6 | Chip Resistor | 100K, 5%, 1/10W; 0603 | Vishay |
| R4 | Chip Resistor | 29.4K, 1%, 1/10W; 0603 | Vishay |
| R2 | Chip Resistor | 78.7K, 1%, 1/10W; 0603 | Vishay |
| R1, R3 | Chip Resistor | 59K, 1%, 1/10W; 0603 | Vishay |
| J1-J4 | PRPN401PAEN | Conn. Header, 2mm Zip | Sullins Electronics |
| LED7 | CMD15-21SRC/TR8 | Red LED; 1206 | Chicago Miniature Lamp |
| SW1-SW3 | PTS645TL50 | Switch Tact, SPST, 5mm | ITT Industries |

ChargePumpTM High Current Charge Pump with Dual LDO for Backlight Applications
Ordering Information

| Package | Marking ¹ | Part Number (Tape and Reel) ² |
|---------------|----------------------|--|
| TQFN44-28-0.4 | YFXYY | AAT2856INJ-EE-T1 |



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Package Information³
TQFN44-28-0.4


All dimensions in millimeters.

1. XYY = assembly and date code.

2. Sample stock is generally held on part numbers listed in **BOLD**.

3. The leadless package family, which includes QFN, TQFN, DFN, TDFN and STDFN, has exposed copper (unplated) at the end of the lead terminals due to the manufacturing process. A solder fillet at the exposed copper edge cannot be guaranteed and is not required to ensure a proper bottom solder connection.



PRODUCT DATASHEET

AAT2856

ChargePump™ High Current Charge Pump with Dual LDO for Backlight Applications

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